



# PJT7808

## 20V N-Channel Enhancement Mode MOSFET

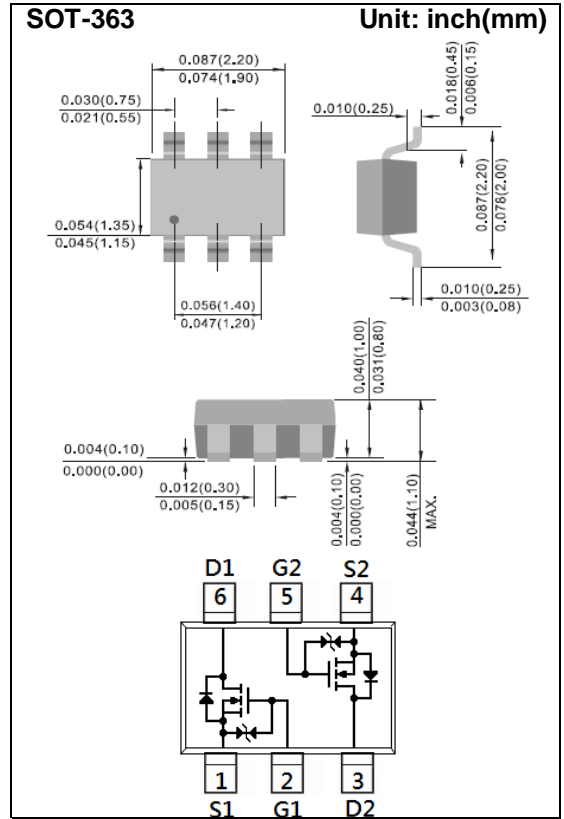
**Voltage** 20 V **Current** 500mA

### Features

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-363 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams
- Marking: T08



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER  | SYMBOL          | LIMIT                           | UNITS                     |                      |
|--|-----------------|---------------------------------|---------------------------|----------------------|
| Drain-Source Voltage                             | $V_{DS}$        | 20                              | V                         |                      |
| Gate-Source Voltage                              | $V_{GS}$        | $\pm 10$                        | V                         |                      |
| Continuous Drain Current                         | $I_D$           | 500                             | mA                        |                      |
| Pulsed Drain Current (Note 4)                    | $I_{DM}$        | 1000                            | mA                        |                      |
| Power Dissipation                                | $P_D$           | $T_a=25^\circ\text{C}$          | 350                       | mW                   |
|  |                 | Derate above $25^\circ\text{C}$ | 2.8                       | mW/ $^\circ\text{C}$ |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$  | -55~150                         | $^\circ\text{C}$          |                      |
| Typical Thermal resistance                       | $R_{\theta JA}$ | 357                             | $^\circ\text{C}/\text{W}$ |                      |
| - Junction to Ambient (Note 3)                   |                 |                                 |                           |                      |



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION  | MIN. | TYP.      | MAX.     | UNITS      |
|---|--------------|---|------|-----------|----------|------------|
| <b>Static</b>   |              |   |      |           |          |            |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$   | 20   | -         | -        | V          |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$   | 0.3  | 0.65      | 0.9      | V          |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=4.5V, I_D=500mA$  | -    | 280       | 400      | m $\Omega$ |
|   |              | $V_{GS}=2.5V, I_D=200mA$  | -    | 350       | 650      |            |
|   |              | $V_{GS}=1.8V, I_D=100mA$  | -    | 400       | 800      |            |
|   |              | $V_{GS}=1.5V, I_D=50mA$   | -    | 500       | 1200     |            |
|   |              | $V_{GS}=1.2V, I_D=20mA$   | -    | 700       | 3000     |            |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=16V, V_{GS}=0V$   | -    | -         | 1        | $\mu A$    |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 8V, V_{DS}=0V$  | -    | $\pm 0.5$ | $\pm 10$ | $\mu A$    |
| <b>Dynamic</b> (Note 5)                               |              |   |      |           |          |            |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=10V, I_D=500mA,$<br>$V_{GS}=4.5V$ (Note 1,2)                    | -    | 1.4       | -        | nC         |
| Gate-Source Charge                                    | $Q_{gs}$     |   | -    | 0.22      | -        |            |
| Gate-Drain Charge                                     | $Q_{gd}$     |   | -    | 0.21      | -        |            |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=10V, V_{GS}=0V,$<br>$f=1.0MHz$                                  | -    | 67        | -        | pF         |
| Output Capacitance                                    | $C_{oss}$    |   | -    | 19        | -        |            |
| Reverse Transfer Capacitance                          | $C_{rss}$    |   | -    | 6         | -        |            |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=10V, I_D=150mA,$<br>$V_{GS}=4.0V,$<br>$R_G=10\Omega$ (Note 1,2) | -    | 2.8       | -        | ns         |
| Turn-On Rise Time                                     | $t_r$        |   | -    | 20        | -        |            |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |   | -    | 23        | -        |            |
| Turn-Off Fall Time                                    | $t_f$        |   | -    | 23        | -        |            |
| <b>Drain-Source Diode</b>                             |              |   |      |           |          |            |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---   | -    | -         | 500      | mA         |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=500mA, V_{GS}=0V$  | -    | 0.87      | 1.3      | V          |

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

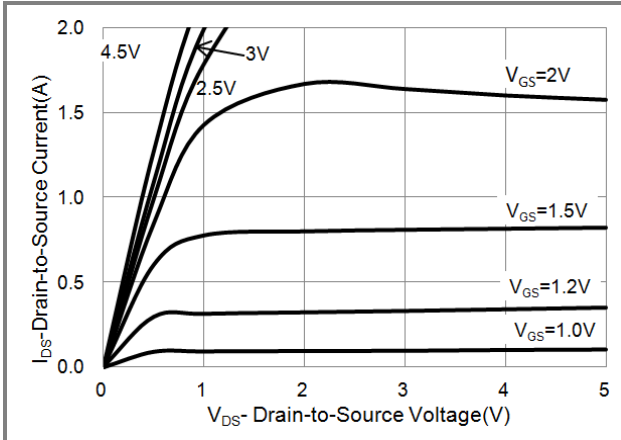


Fig.1 On-Region Characteristics

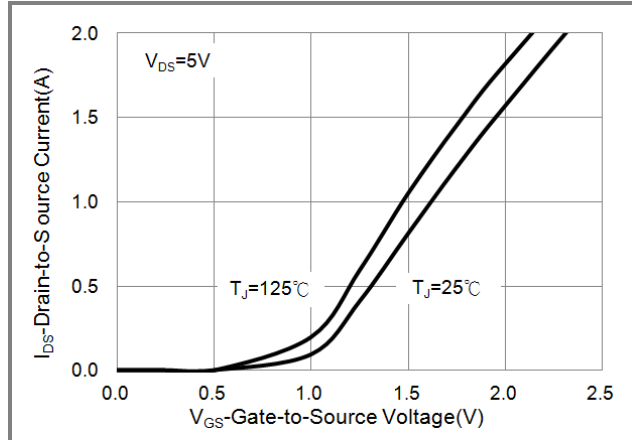


Fig.2 Transfer Characteristics

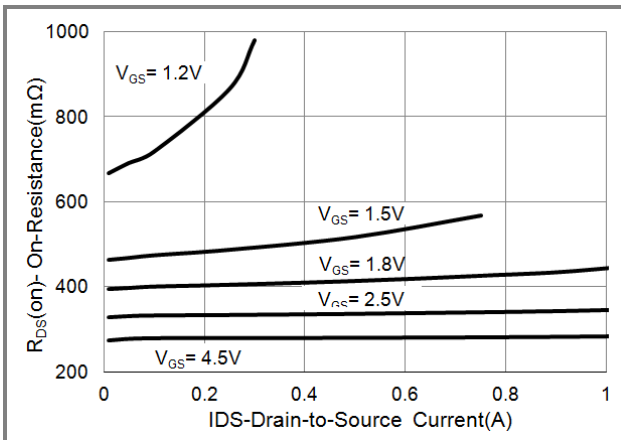


Fig.3 On-Resistance vs. Drain Current

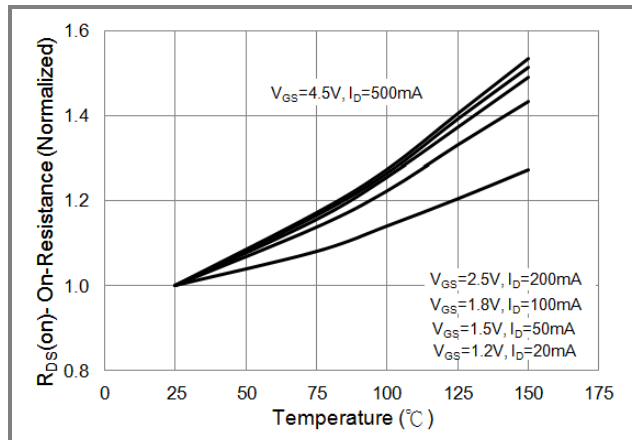


Fig.4 On-Resistance vs. Junction temperature

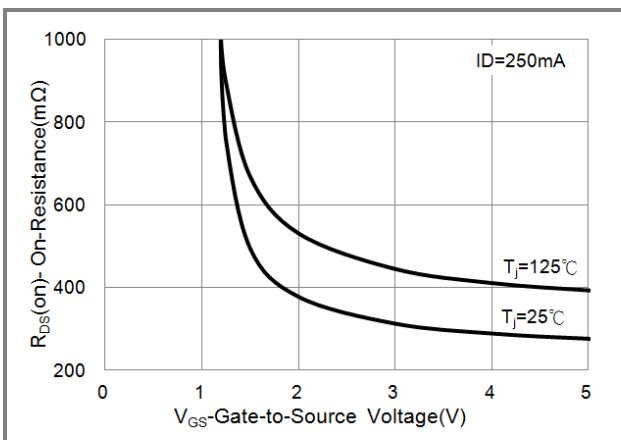


Fig.5 On-Resistance Variation with VGS.

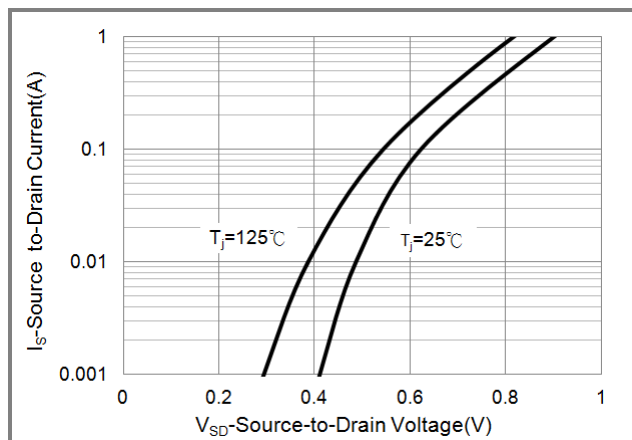


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

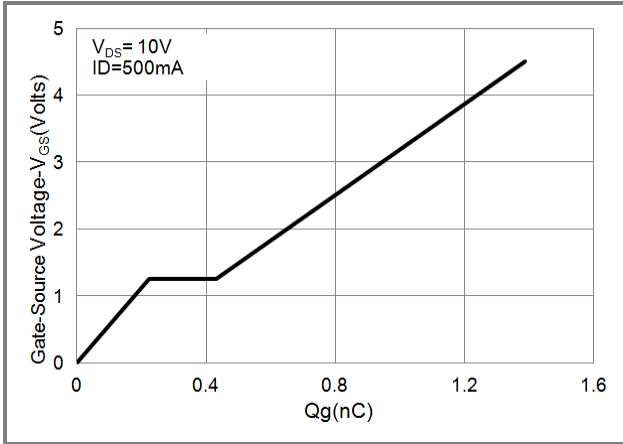


Fig.7 Gate-Charge Characteristics

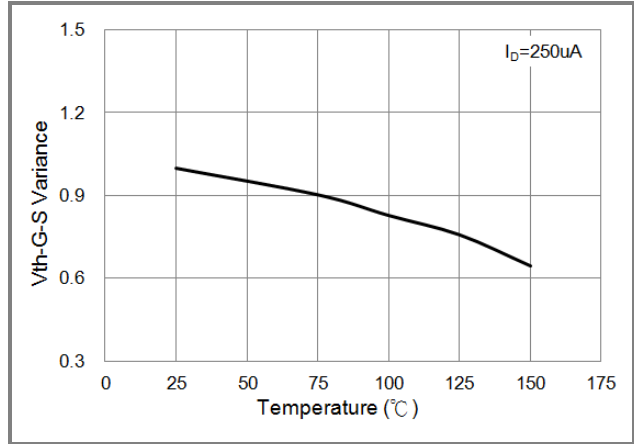


Fig.8 Threshold Voltage Variation with Temperature.

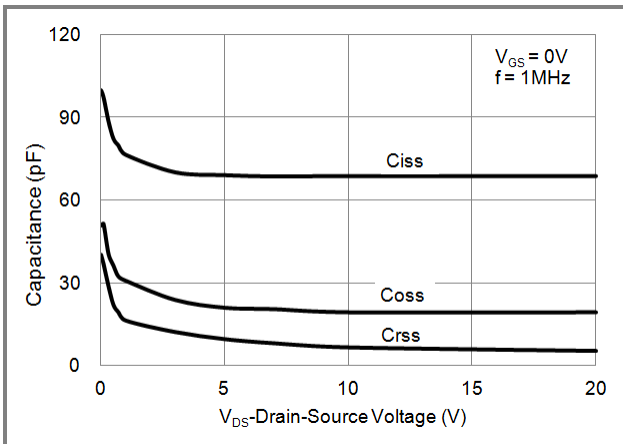


Fig.9 Capacitance vs. Drain-Source Voltage.

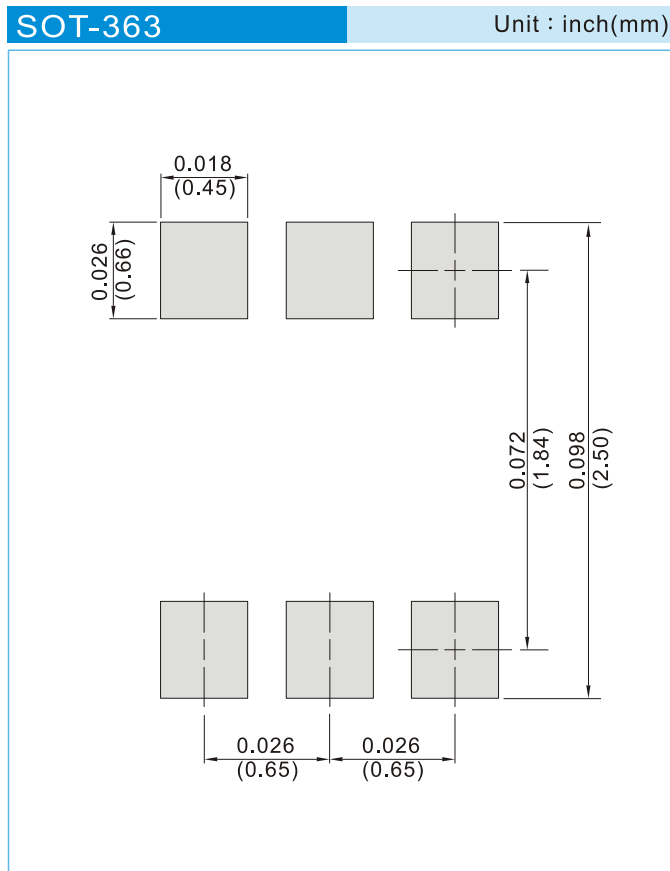


# PJT7808

## PART NO PACKING CODE VERSION

| PART NO PACKING CODE | Package Type | Packing type       | Marking | Version      |
|----------------------|--------------|--------------------|---------|--------------|
| PJT7808_R1_00001     | SOT-363      | 3K pcs / 7" reel   | T08     | Halogen free |
| PJT7808_R2_00001     | SOT-363      | 10K pcs / 13" reel | T08     | Halogen free |

## MOUNTING PAD LAYOUT





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